

# SANYO Semiconductors DATA SHEET

# 2SC4736 — High hFE, Low-Frequency General-Purpose Amplifier Applications

#### **Features**

- Large current (IC=2A).
- · Adoption of MBIT process.
- · High DC current gain (hFE=800 to 3200).
- · Low collector-to-emitter saturation voltage (VCE(sat)≤0.5V).
- · High emitter-to-base voltage (VEBO≥15V).
- Large power type such as PC=1.5W when used without heatsink.
- It is possible to make appliances more compact because its height on board is 9.5mm.
- · Effective in automatic inserting and counting stocked amount because of being provided for radial taping.

### **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

| Parameter                    | Symbol | Conditions | Ratings     | Unit |
|------------------------------|--------|------------|-------------|------|
| Collector-to-Base Voltage    | VCBO   |            | 80          | V    |
| Collector-to-Emitter Voltage | VCEO   |            | 60          | V    |
| Emitter-to-Base Voltage      | VEBO   |            | 15          | V    |
| Collector Current            | IC     |            | 2           | Α    |
| Collector Current (Pulse)    | ICP    |            | 4           | Α    |
| Base Current                 | IB     |            | 400         | mA   |
| Collector Dissipation        | PC     |            | 1.5         | W    |
| Junction Temperature         | Tj     |            | 150         | °C   |
| Storage Temperature          | Tstg   |            | -55 to +150 | °C   |

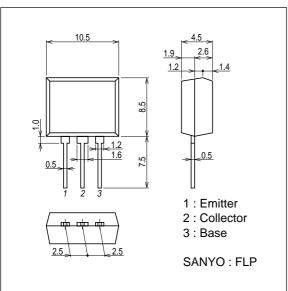
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# Electrical Characteristics at Ta=25°C

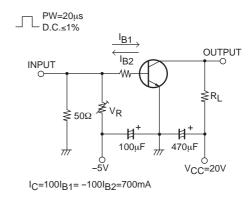
| Parameter                               | Symbol                | Conditions                                 | Ratings |      |      | Unit  |
|---|-----------------------|--|---------|------|------|-------|
|   |                       |  | min     | typ  | max  | Offic |
| Collector Cutoff Current                | ІСВО                  | VCB=50V, IE=0A                             |         |      | 1    | μΑ    |
| Emitter Cutoff Current                  | IEBO                  | V <sub>EB</sub> =10V, I <sub>C</sub> =0A   |         |      | 1    | μΑ    |
| DC Current Gain                         | hFE1                  | VCE=5V, IC=500mA                           | 800     | 1500 | 3200 |       |
|   | hFE2                  | VCE=5V, IC=1A                              | 600     |      |      |       |
| Gain-Bandwidth Product                  | fT                    | V <sub>CE</sub> =10V, I <sub>C</sub> =50mA |         | 170  |      | MHz   |
| Output Capacitance                      | Cob                   | V <sub>CB</sub> =10V, f=1MHz               |         | 24   |      | pF    |
| Collector-to-Emitter Saturation Voltage | V <sub>CE</sub> (sat) | I <sub>C</sub> =1A, I <sub>B</sub> =20mA   |         | 0.2  | 0.5  | V     |
| Base-to-Emitter Saturation Voltage      | V <sub>BE</sub> (sat) | I <sub>C</sub> =1A, I <sub>B</sub> =20mA   |         | 0.87 | 1.2  | V     |
| Collector-to-Base Breakdown Voltage     | V(BR)CBO              | IC=10μA, IE=0A                             | 80      |      |      | V     |
| Collector-to-Emitter Breakdown Voltage  | V(BR)CEO              | I <sub>C</sub> =1mA, R <sub>BE</sub> =∞    | 60      |      |      | V     |
| Emitter-to-Base Breakdown Voltage       | V(BR)EBO              | I <sub>E</sub> =10μA, I <sub>C</sub> =0A   | 15      |      |      | V     |
| Turn-ON Time                            | ton                   | See specified Test Circuit.                |         | 0.23 |      | μS    |
| Storage Time                            | tstg                  | See specified Test Circuit.                |         | 2.7  |      | μS    |
| Fall Time                               | tf                    | See specified Test Circuit.                |         | 0.75 |      | μS    |

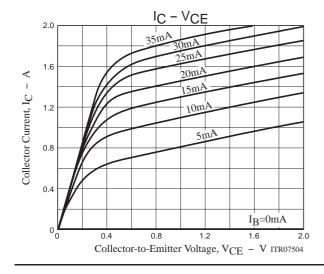
# **Package Dimensions**

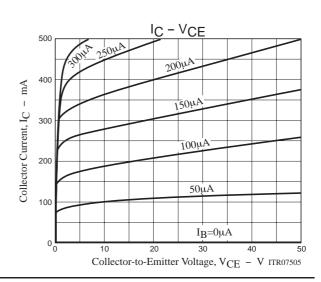
unit : mm (typ) 7514-003

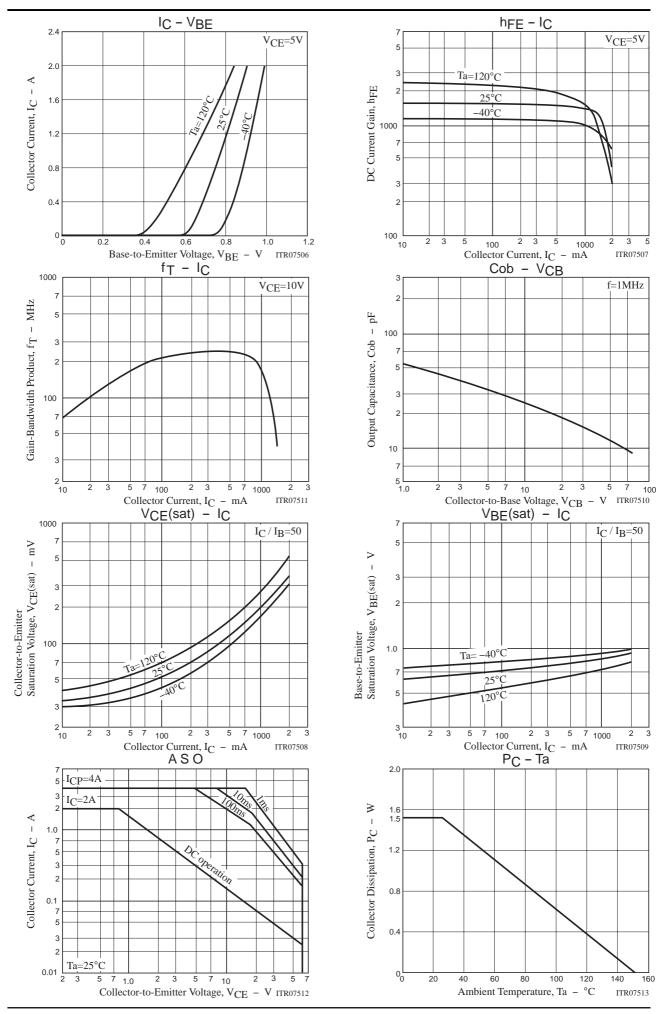


# **Switching Time Test Circuit**









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